

KA2S0765

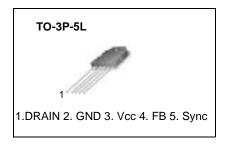
Fairchild Power Switch(FPS)

Features

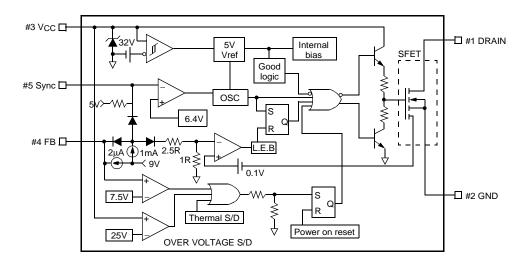
- Wide operating frequency range up to (150kHz)
- Pulse by pulse over current limiting
- · Over load protection
- Over voltage protecton (Min. 23V)
- · Internal thermal shutdown function
- Under voltage lockout
- Internal high voltage sense FET
- · External sync terminal
- · Latch up Mode

Description

The Fairchild Power Switch(FPS) product family is specially designed for an off line SMPS with minimal external components. The Fairchild Power Switch(FPS) consist of high voltage power SenseFET and current mode PWM controller IC. control IC features a trimmed oscillator, under voltage lock-out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, temperature compensated precision current sources for loop compensation and fault protection circuit. compared to discrete MOSFET and controller or RCC switching converter solution, a Fairchild Power Switch(FPS) can reduce total component count, design size, weight and at the same time increase & efficiency, productivity, and system reliability. It has a basic platform well suited for cost-effective Monitor power supply.



Internal Block Diagram



Absolute Maximum Ratings

Characteristic	Symbol	Value	Unit	
Maximum Drain voltage (1)	VD,MAX	650	V	
Drain Gate voltage (R _{GS} =1MΩ)	VDGR	650	V	
Gate source (GND) voltage	VGS	±30	V	
Drain current pulsed (2)	IDM	28.0	ADC	
Single pulsed avalanche energy (3)	EAS	570	mJ	
Continuous drain current (Tc=25°C)	ΙD	7.0	ADC	
Continuous drain current (Tc=100°C)	ΙD	5.6	ADC	
Maximum Supply voltage	VCC,MAX	30	V	
Input voltage range	VFB	-0.3 to VSD	V	
Total navor discination	PD	140	W	
Total power dissipation	Derating	1.11	W/°C	
Operating ambient temperature	TA	-25 to +85	°C	
Storage temperature	T _{STG}	-55 to +150	°C	

Note:

- 1. Tj=25°C to 150°
- 2. Repetitive rating: Pulse width limited by maximum junction temperature
- 3. L=24mH, VDD=50V, RG=25 Ω , starting Tj=25 °C

Electrical Characteristics (SFET part)

(Ta = 25°C unless otherwise specified)

Characteristic	Symbol	Test condition	Min.	Тур.	Max.	Unit
Drain source breakdown voltage	BVDSS	VGS=0V, ID=50μA	650	-	-	V
Zero gate voltage drain current	IDSS	VDS=Max., Rating, VGS=0V	-	-	50	μА
		V _{DS} =0.8Max., Rating, V _{GS} =0V, T _C =125°C	-	-	200	mA
Static drain source on resistance (note)	RDS(ON)	VGS=10V, ID=4.0A	-	1.25	1.6	W
Forward transconductance (note)	gfs	V _{DS} =15V, I _D =4.0A	3.0	-	-	S
Input capacitance	Ciss	\\ 0\\ \\ 0\\	-	1600	-	
Output capacitance	Coss	VGS=0V, VDS=25V, f=1MHz	-	310	-	pF
Reverse transfer capacitance	Crss	1 - 11/11/2	-	120	-	
Turn on delay time	td(on)	VDD=0.5BVDSS, ID=7.0A (MOSFET switching time are essentially independent of operating temperature)	-	25	-	
Rise time	tr		-	55	-	
Turn off delay time	td(off)		-	80	-	nS
Fall time	tf		1	50	1	
Total gate charge (gate-source+gate-drain)	Qg	VGS=10V, ID=7.0A, VDS=0.5BVDSS (MOSFET switching time are essentially independent of operating temperature)	-	-	72	
Gate source charge	Qgs		-	9.3	-	nC
Gate drain (Miller) charge	Qgd		-	29.3	-	

Note:

Pulse test: Pulse width $\leq 300 \mu S$, duty cycle $\leq 2\%$ $S = \frac{1}{R}$

Electrical Charcteristics (CONTROL part)

(Ta = 25°C unless otherwise specified)

Characteristic	Symbol	Test condition	Min.	Тур.	Max.	Unit	
UVLO SECTION							
Start threshold voltage	VSTART	-	14	15	16	V	
Stop threshold voltage	VSTOP	After turn on	9	10	11	V	
OSCILLATOR SECTION							
Initial accuracy	Fosc	Ta=25°C	18	20	22	kHz	
Frequency change with temperature (2)	ΔΕ/ΔΤ	–25°C ≤ Ta ≤ +85°C	-	±5	±10	%	
Maximum duty cycle	D _{max}	-	92	95	98	%	
FEEDBACK SECTION	FEEDBACK SECTION						
Feedback source current	IFB	Ta=25°C, Vfb=GND	0.7	0.9	1.1	mA	
Shutdown Feedback voltage	VsD	-	6.9	7.5	8.1	V	
Shutdown delay current	I _{delay}	Ta=25°C, 5V ≤ Vfb ≤ V _{SD}	1.4	1.8	2.2	μΑ	
SYNC. & SOFT START SECTION							
Soft start voltage	Vss	VFB=2V	4.7	5.0	5.3	V	
Soft start current	Iss	Sync & S/S=GND	8.0	1.0	1.2	mA	
Sync threshold voltage ⁽³⁾	Vsyth	Vfb=5V	6.0	6.4	6.8	V	
REFERENCE SECTION							
Output voltage (1)	Vref	Ta=25°C	4.80	5.00	5.20	V	
Temperature Stability (1)(2)	Vref/∆T	–25°C ≤ Ta ≤ +85°C	-	0.3	0.6	mV/°C	
CURRENT LIMIT (SELF-PROTECTION) SECTION							
Peak Current Limit	IOVER	KA2S0765	4.40	5.00	5.60	Α	
PROTECTION SECTION							
Thermal shutdown temperature (Tj) (1)	TSD	-	140	160	-	°C	
Over voltage protection voltage	Vovp	-	23	25	28	V	
TOTAL DEVICE SECTION							
Start Up current	ISTART	Vcc=14V	0.1	0.3	0.55	mA	
Operating supply current (control part only)	IOP	Ta=25°C	6	12	18	mA	
VCC zener voltage	Vz	ICC=20mA	30	32.5	35	V	

Note:

- 1. These parameters, although guaranteed, are not 100% tested in production
- 2. These parameters, although guaranteed, are tested in EDS(water test) process
- 3. The amplitude of the sync. pulse is recommended to be between 2V and 3V for stable sync. function.

Typical Performance Characteristics

(These characteristic graphs are normalized at Ta = 25°C)

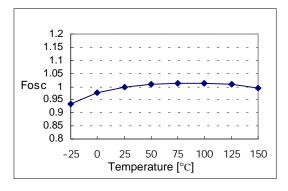


Figure 1. Operating Frequency

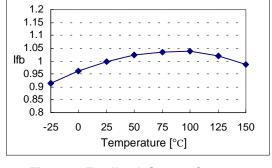


Figure 2. Feedback Source Current

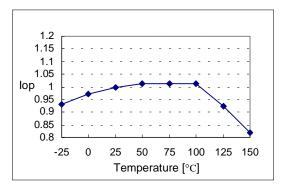


Figure 3. Operating Supply Current

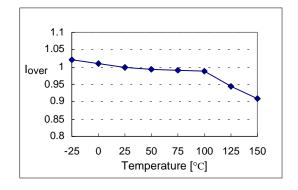


Figure 4. Peak Current Limit

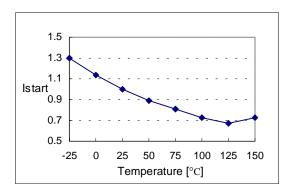


Figure 5. Start up Current

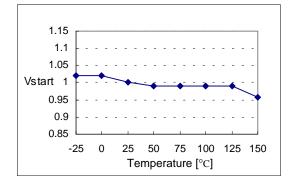


Figure 6. Start Threshold Voltage

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta = 25°C)

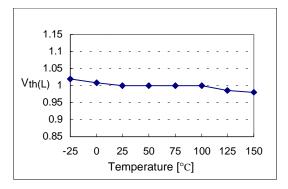


Figure 7. Stop Threshold Voltage

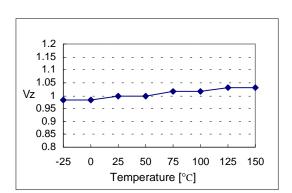


Figure 9. VCC Zener Voltage

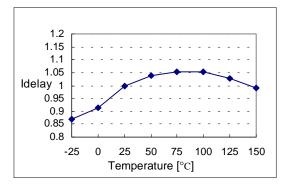


Figure 11. Shutdown Delay Current

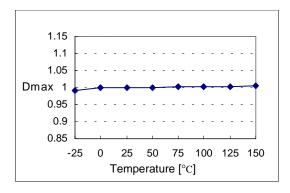


Figure 8. Maximum Duty Cycle

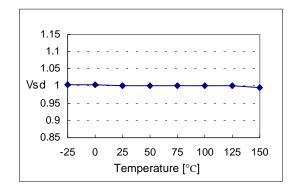


Figure 10. Shutdown Feedback Voltage

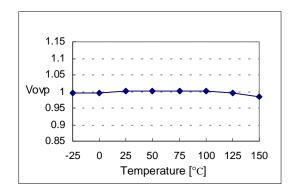


Figure 12. Over Voltage Protection

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at $Ta = 25^{\circ}C$)

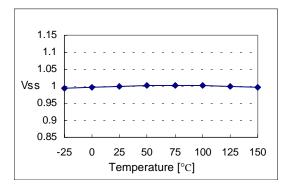


Figure 13. Soft Start Voltage

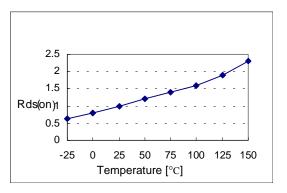
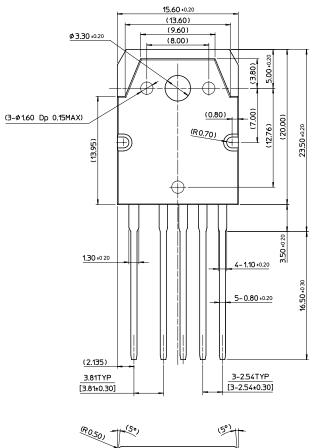
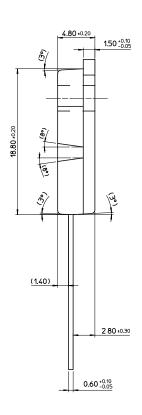


Figure 14. Static Drain-Source on Resistance

Package Dimensions

TO-3P-5L

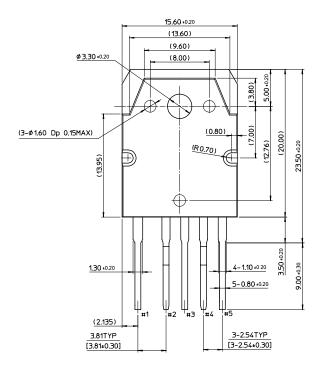


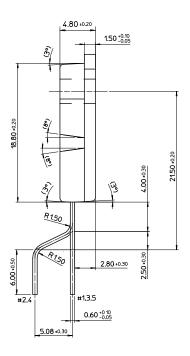


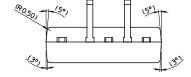


Package Dimensions (Continued)

TO-3P-5L (Forming)







Ordering Information

Product Number	Package	Rating	Operating Temperature		
KA2S0765-TU	TO-3P-5L	650V.7A	-25°C to +85°C		
KA2S0765-YDTU	TO-3P-5L(Forming)	030V,7A	-23 C to +63 C		

TU: Non Forming Type YDTU: Forming Type

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